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U.S. UTILITY Patent Application

PATENT NUMBER and
ISSUE DATE

APPL NUM	FILING DATE	CLASS	SUBCLASS	GAU	EXAMINER
10075193	02/13/2002	438	253	2813	YORK HUYNH

**APPLICANTS: Chen Shennin; Fing Er-Xuan; *YH*

**CONTINUING DATA VERIFIED:
THIS APPLICATION IS A DIV OF 09/933,913 08/20/2001 *yes*

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** FOREIGN APPLICATIONS VERIFIED: *none*

PG-PUB	DO NOT PUBLISH <input type="checkbox"/>	RESCIND <input type="checkbox"/>	ATTORNEY DOCKET NO
Foreign priority claimed <input type="checkbox"/> yes <input checked="" type="checkbox"/> no		MI22-1927	
35 USC 119 conditions met <input type="checkbox"/> yes <input checked="" type="checkbox"/> no			
Verified and Acknowledged Examiners's initials <i>YH</i>			
TITLE : Methods of forming a capacitor structure			

U.S. DEPT. OF COMM./PAT. & TM.-PTO-435L (Rev. 12-94)

NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED	
		Total Claims	Print Claim for O.G.
ISSUE FEE		DRAWING	
Amount Due	Date Paid	Sheets Drwg.	Figs. Drwg. Print Fig.
TERMINAL DISCLAIMER <input type="checkbox"/>		Application Examiner	
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